NSN 5961-01-162-8446

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-162-8446 **Inclosure Material:** Metal **Overall Length:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to emitter voltage/static/base open and 500.0 collector to base voltage/static/emitter open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Internal surfaces gold **Precious Material:** Gold **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud

N/a

Shelf Life:

Unit Of Measure:

NSN 5961-01-162-8446

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0